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Vishay Siliconix

P-Channel 20 V (D-S) MOSFET

DESCRIPTION

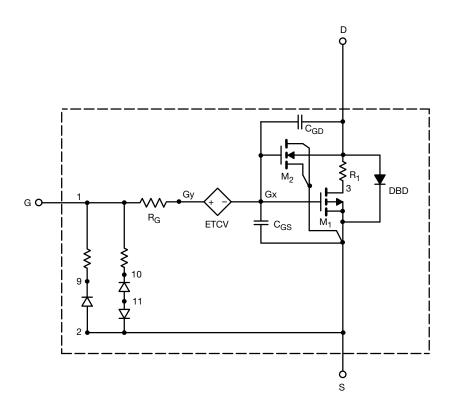
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 $^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$ temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over the -55 °C to +125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	0.74	-	V
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$	0.076	0.077	Ω
		$V_{GS} = -2.5 \text{ V}, I_D = -1 \text{ A}$	0.105	0.100	
Forward transconductance a	9 _{fs}	V _{DS} = -5 V, I _D = -1 A	5.2	6	S
Diode forward voltage	V _{SD}	I _S = -1 A	-0.73	-0.80	V
Dynamic ^b					
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	724	580	pF
Output capacitance	Coss		77	75	
Reverse transfer capacitance	C _{rss}		66	65	
Total gate charge	Qg	$V_{DS} = -10 \text{ V}, V_{GS} = -8 \text{ V}, I_D = -1 \text{ A}$	10	11	- nC
		$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -1 \text{ A}$	5.8	6.6	
Gate-source charge	Q _{gs}		1	1	
Gate-drain charge	Q_{gd}		1.5	1.5	

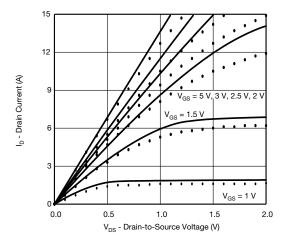
Notes

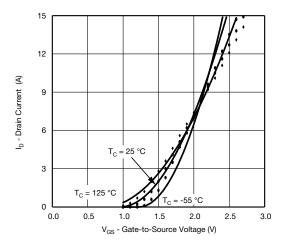
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

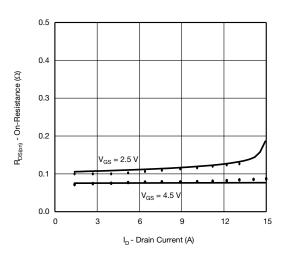
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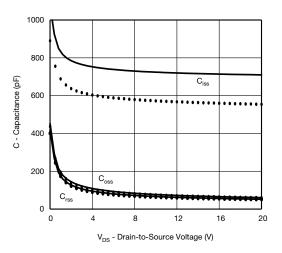
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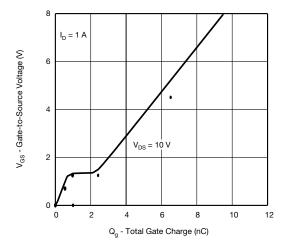
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}\text{C}$, unless otherwise noted)

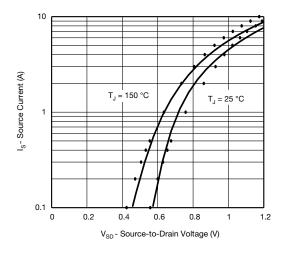












Note

 Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.



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